

Boost Chopper

SKiiP26GAL12T4V1

Features*

- Trench 4 IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532
- NTC T-Sensor

Remarks

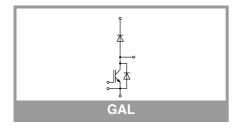
- Max. case temperature limited to T_C=125°C
- Product reliability results valid for T_j≤150°C (recommended T_{j,op}=-40...+150°C)
 MiniSKiiP "Technical Explanations"
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information
- For storage and case temperature with TIM see document: "Technical Explanations Thermal Interface Materials"
- Diode 1 = D1
- Diode 2 = D2
- IGBT 1 = T2

Absolute	Maximum Ratings	5		
Symbol	Conditions		Values	Unit
IGBT 1				•
V_{CES}	T _j = 25 °C		1200	V
Ic	$\lambda_{paste}=0.8 \text{ W/(mK)}$	T _s = 25 °C	209	Α
	T _j = 175 °C	T _s = 70 °C	169	Α
I _C	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	289	Α
	T _j = 175 °C	T _s = 70 °C	236	Α
I _{Cnom}			200	Α
I _{CRM}			600	Α
V_{GES}			-20 20	V
t _{psc}	$V_{CC} = 800 \text{ V}$ $V_{GE} \le 15 \text{ V}$ $V_{CES} \le 1200 \text{ V}$	T _j = 150 °C	10	μs
Tj			-40 175	°C

Absolute Maximum Ratings						
Symbol	Conditions		Values	Unit		
Diode 1				•		
V_{RRM}	T _j = 25 °C		1200	V		
I _F	λ_{paste} =0.8 W/(mK) T _j = 175 °C	T _s = 25 °C	174	Α		
		T _s = 70 °C	138	Α		
I _F	λ_{paste} =2.5 W/(mK) T _j = 175 °C	T _s = 25 °C	219	Α		
		T _s = 70 °C	174	Α		
I _{FRM}			400	Α		
I _{FSM}	10 ms	T _j = 25 °C	990	Α		
	sin 180°	T _j = 150 °C	990	Α		
T _i			-40 175	°C		

Absolute Maximum Ratings						
Symbol	Conditions		Values	Unit		
Diode 2				•		
V_{RRM}	T _j = 25 °C		1200	V		
l _F	λ _{paste} =0.8 W/(mK)	T _s = 25 °C	14	Α		
	T _j = 175 °C	T _s = 70 °C	12	Α		
I _F	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	15	Α		
	T _j = 175 °C	T _s = 70 °C	12	Α		
I _{FRM}			16	Α		
I _{FSM}	10 ms	T _j = 25 °C	36	Α		
	sin 180°	T _j = 150 °C	36	Α		
Tj			-40 175	°C		

Absolute Maximum Ratings					
Symbol	Conditions	Values	Unit		
Module					
I _{t(RMS)}	20 A per spring	200	Α		
T _{stg}	module without TIM	-40 125	°C		
V _{isol}	AC sinus 50 Hz, t = 1 min	2500	V		





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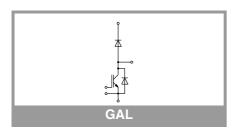
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Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
IGBT 1			•			
V _{CE(sat)}	I _C = 200 A	T _j = 25 °C		1.80	2.05	V
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.20	2.40	V
V_{CE0}	cnipievei	T _j = 25 °C		0.80	0.90	V
		T _j = 150 °C		0.70	0.80	V
r _{CE}	GL -	T _j = 25 °C		5.0	5.8	mΩ
	chiplevel	T _j = 150 °C		7.5	8.0	mΩ
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_{C} = 12 \text{ r}$	nA	5	5.8	6.5	V
I _{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 12$	00 V, T _j = 25 °C			2.0	mA
C _{ies}	$V_{CE} = 25 \text{ V}$ $V_{GF} = 0 \text{ V}$	f = 1 MHz		12.30		nF
Coes		f = 1 MHz		0.81		nF
C _{res}		f = 1 MHz		0.69		nF
Q_{G}	V _{GE} = - 8 V+ 15 V			1130		nC
R _{Gint}	T _j = 25 °C			3.8		Ω
t _{d(on)}	V _{CC} = 600 V	T _j = 150 °C		170		ns
t _r	I _C = 200 A	T _j = 150 °C		45		ns
E _{on}	$V_{GE} = +15/-15 \text{ V}$ $R_{G \text{ on}} = 2 \Omega$	T _j = 150 °C		13.6		mJ
t _{d(off)}	$R_{G \text{ off}} = 2 \Omega$	T _j = 150 °C		440		ns
t _f	$\begin{array}{l} \text{di/dt}_{\text{on}} = 5500 \text{ A/}\mu\text{s} \\ \text{di/dt}_{\text{off}} = 2000 \text{ A/}\mu\text{s} \end{array}$	T _j = 150 °C		91		ns
E _{off}		T _j = 150 °C		22.1		mJ
R _{th(j-s)}	per IGBT, λ _{paste} =0.8	3 W/(mK)		0.28		K/W
R _{th(j-s)}	per IGBT, λ _{paste} =2.5	5 W/(mK)		0.16		K/W

Characteristics							
Symbol	Conditions		min.	typ.	max.	Unit	
Diode 1							
V _F	I _F = 200 A	T _j = 25 °C		2.20	2.52	V	
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.15	2.47	V	
V_{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V	
		T _j = 150 °C		0.90	1.10	V	
r _F	chiplevel	T _j = 25 °C		4.5	5.1	mΩ	
	Chipievei	T _j = 150 °C		6.3	6.9	mΩ	
I _{RRM}	I _F = 200 A	T _j = 150 °C		228		Α	
Q _{rr}	$di/dt_{off} = 5215 \text{ A/}\mu\text{s}$ $V_{GF} = -15 \text{ V}$	T _j = 150 °C		32		μC	
Err	$V_{GE} = -15 \text{ V}$ $V_{CC} = 600 \text{ V}$	T _j = 150 °C		13.4		mJ	
R _{th(j-s)}	per Diode, λ _{paste} =0.	8 W/(mK)		0.4		K/W	
R _{th(j-s)}	per Diode, λ _{paste} =2.	5 W/(mK)		0.28		K/W	





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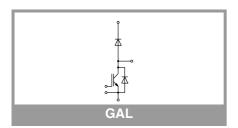
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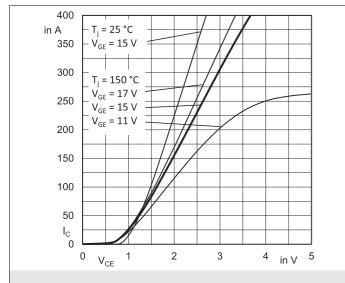
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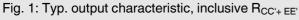
Characte	Characteristics							
Symbol	Conditions		min.	typ.	max.	Unit		
Diode 2	·							
V_{F}	I _F = 8 A	T _j = 25 °C		2.33	2.65	V		
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.35	2.68	V		
V_{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V		
		T _j = 150 °C		0.90	1.10	V		
r _F	chiplevel	T _j = 25 °C		129	144	mΩ		
	Chipievei	T _j = 150 °C		181	198	mΩ		
I _{RRM}	I _F = 8 A	T _j = 150 °C		t.b.d.		Α		
Q _{rr}	V _{GE} = -15 V	T _j = 150 °C		t.b.d.		μC		
E _{rr}	$V_{CC} = 600 \text{ V}$	T _j = 150 °C		t.b.d.		mJ		
R _{th(j-s)}	per Diode, λ _{paste} =0.8 W/(mK)			2.8		K/W		
R _{th(j-s)}	per Diode, λ _{paste} =	2.5 W/(mK)		2.6		K/W		

Characteristics						
Symbol	Conditions	min.	typ.	max.	Unit	
Module						
Ms	to heat sink	2		2.5	Nm	
W	weight		55		g	

Characteristics						
Symbol	Conditions	min.	typ.	max.	Unit	
Temperature Sensor						
R ₁₀₀	T _c =100°C (R ₂₅ =5 kΩ)	493 ± 5%			Ω	
B _{25/85}	$R_{(T)} = R_{25} * \exp[B_{25/85} * (1/T-1/298)], T[K]$		3420		K	







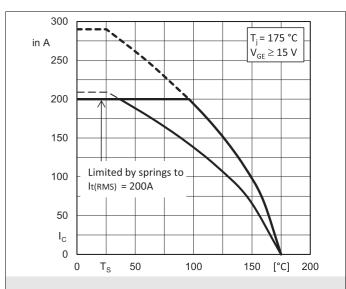


Fig. 2: Rated current vs. temperature $I_C = f(T_S)$

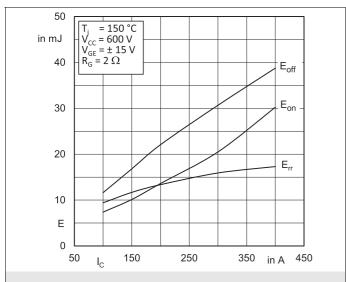


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

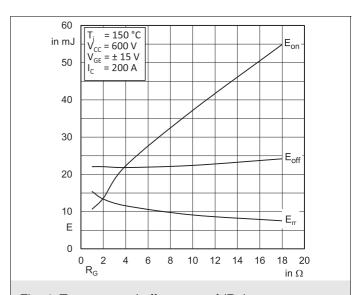


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

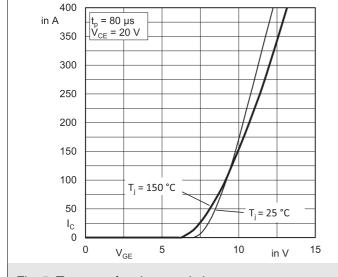


Fig. 5: Typ. transfer characteristic

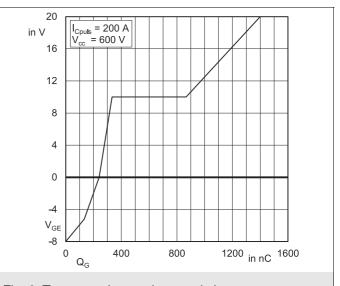
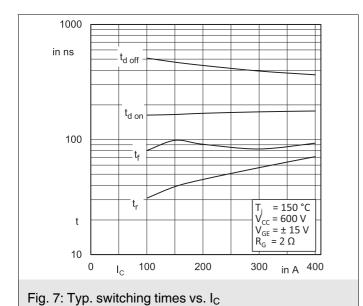


Fig. 6: Typ. gate charge characteristic



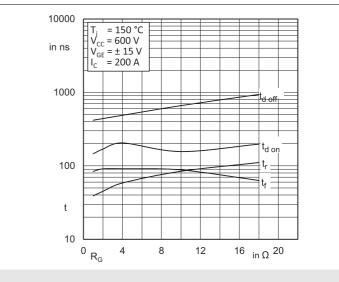
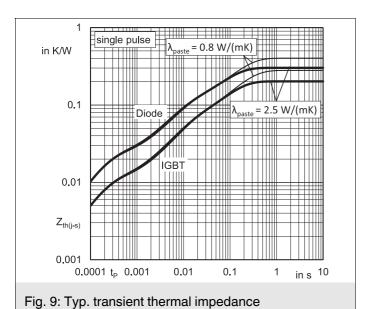


Fig. 8: Typ. switching times vs. gate resistor R_{G}



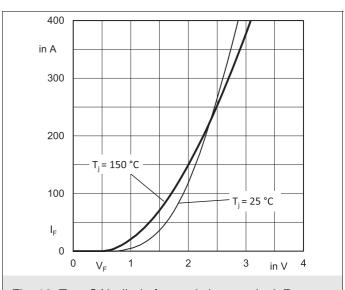
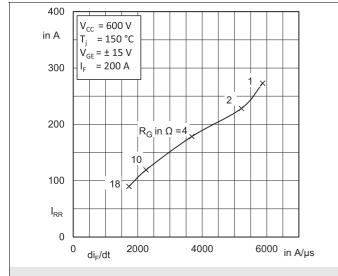


Fig. 10: Typ. CAL diode forward charact., incl. R_{CC'+ EE'}



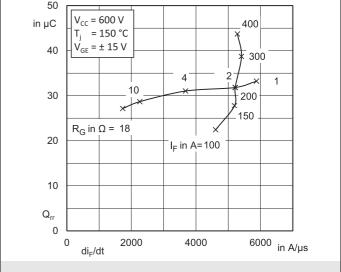
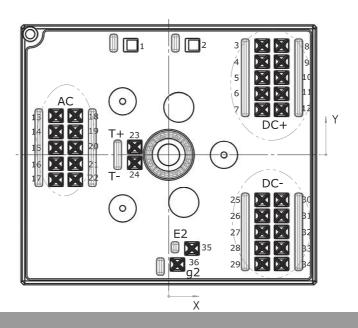


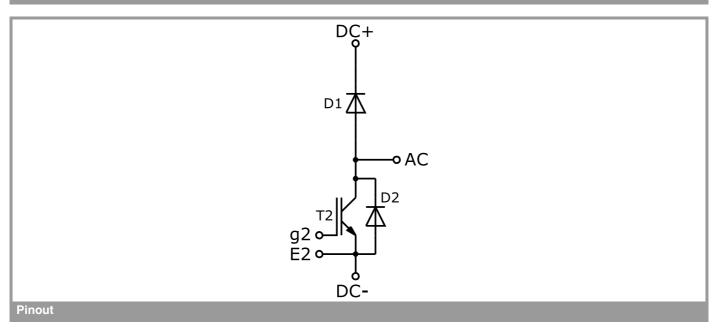
Fig. 11: Typ. CAL diode peak reverse recovery current Fig. 12: Typ. CAL diode recovery charge

			Pin	out	-		
Pin	X	Υ	Function	Pin	X	Υ	Function
1	-7,58	21,9		19	-18,63	4,6	AC
2	4,73	21,9		20	-18,63	1,4	AC
3	18,63	21,8	DC+	21	-18,63	-1,8	AC
4	18,63	18,6	DC+	22	-18,63	-5	AC
5	18,63	15,4	DC+	23	-6,78	1,6	T+
6	18,63	12,2	DC+	24	-6,78	-1,6	T-
7	18,63	9	DC+	25	18,63	-9	DC-
8	22,48	21,8	DC+	26	18,63	-12,2	DC-
9	22,48	18,6	DC+	27	18,63	-15,4	DC-
10	22,48	15,4	DC+	28	18,63	-18,6	DC-
11	22,48	12,2	DC+	29	18,63	-21,8	DC-
12	22,48	9	DC+	30	22,48	-9	DC-
13	-22,48	7,8	AC	31	22,48	-12,2	DC-
14	-22,48	4,6	AC	32	22,48	-15,4	DC-
15	-22,48	1,4	AC	33	22,48	-18,6	DC-
16	-22,48	-1,8	AC	34	22,48	-21,8	DC-
17	-22,48	-5	AC	35	4,63	-18,7	E2
18	-18,63	7,8	AC	36	1,73	-21,9	g2

all values in mm



Pinout and Dimensions



This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

*IMPORTANT INFORMATION AND WARNINGS

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